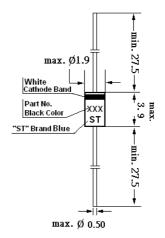
SILICON PLANAR ZENER DIODES



Glass case JEDEC DO-35
Dimensions in mm

Absolute Maximum Ratings (T_a = 25 °C)

	Symbol	Value	Unit			
Power Dissipation	P _{tot}	500 ¹⁾	mW			
Junction Temperature	T _j	175	°C			
Storage Temperature Range	T _S	-55 to +175	°C			
1) Valid provided that leads are kept at ambient temperature at a distance of 8 mm from case						

Characteristics at T_{amb} = 25 °C

	Symbol	Min.	Max.	Unit
Thermal Resistance Junction to Ambient Air	R _{thA}	-	0.3 ¹⁾	K/mW
Forward Voltage at I _F = 200mA	V _F	-	1.2	V

¹⁾ Valid provided that leads are kept at ambient temperature at a distance of 8 mm from case

Characteristics at T_{amb} = 25 °C

Torre	Zener Voltage Range ¹⁾		Dynamic Resistance		Leakage Current		Maximum DC Zener Current		
Туре	V_{znom}	I_{ZT} for $V_{ZT}^{(2)}$		r _{zJT} r _{zJK} at I _{zK}		I _R at V _R		I _{ZM}	
	V	mΑ	V	Ω	Ω	mA	μA	V	mA
1N6008B	22	5	20.923.1	<55	<600	0.25	<100	17	23

¹⁾ Tested with pulses $t_p = 20$ ms.



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²⁾ Valid provided that leads are kept at ambient temperature at a distance of 8 mm from case.